

TC74VHC174F, TC74VHC174FN, TC74VHC174FT

Hex D-Type Flip Flop with Clear

The TC74VHC174 is an advanced high speed CMOS HEX D-TYPE FLIP FLOP fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Information signals applied to D inputs are transferred to the Q output on the positive going edge of the clock pulse.

When the CLR input is held low, the Q output are in the low logic level independent of the other inputs.

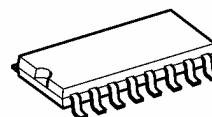
An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

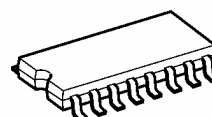
- High speed: $f_{\max} = 150 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu\text{A}$ (max) at $T_a = 25^\circ\text{C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC}(\text{opr}) = 2 \text{ to } 5.5 \text{ V}$
- Low noise: $V_{OLP} = 0.8 \text{ V}$ (max)
- Pin and function compatible with 74ALS174

Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74VHC174F

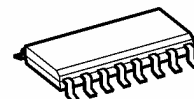


SOP16-P-300-1.27A



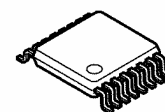
SOP16-P-300-1.27

TC74VHC174FN



SOL16-P-150-1.27

TC74VHC174FT

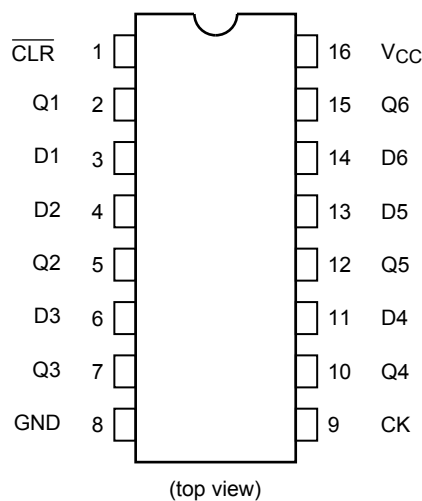


TSSOP16-P-0044-0.65A

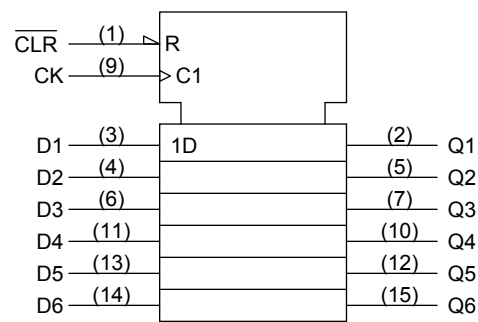
Weight

SOP16-P-300-1.27A	: 0.18 g (typ.)
SOP16-P-300-1.27	: 0.18 g (typ.)
SOL16-P-150-1.27	: 0.13 g (typ.)
TSSOP16-P-0044-0.65A	: 0.06 g (typ.)

Pin Assignment



IEC Logic Symbol

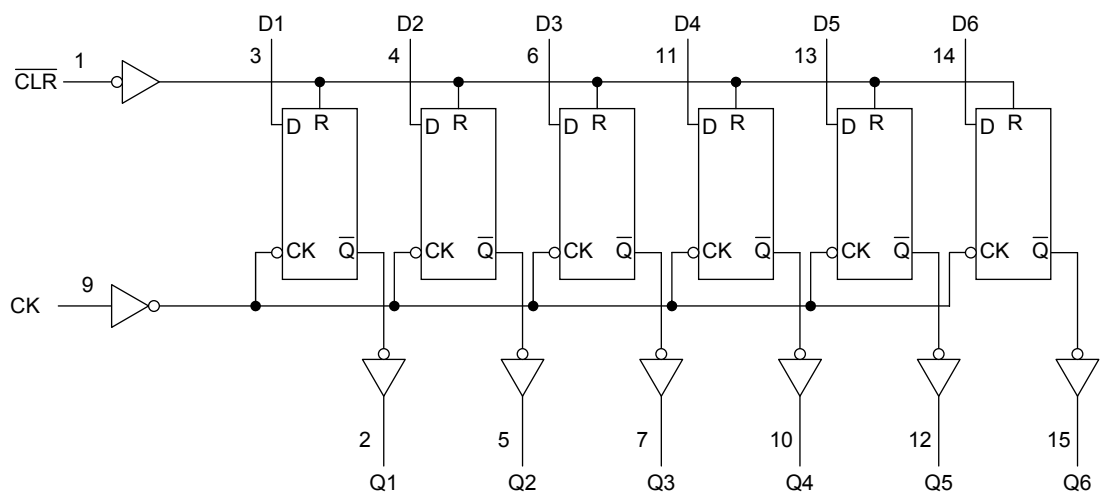


Truth Table

Inputs			Output	Function
CLR	D	CK	Q	
L	X	X	L	Clear
H	L		L	—
H	H		H	—
H	X		Q _n	No Change

X: Don't care

System Diagram



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to 7.0	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V) 0 to 20 ($V_{CC} = 5 \pm 0.5$ V)	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V _{CC} (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V _{IH}	—		2.0 3.0 to 5.5	1.50 V _{CC} × 0.7	— —	— —	1.50 V _{CC} × 0.7	— —	V
Low-level input voltage	V _{IL}	—		2.0 3.0 to 5.5	— —	— —	0.50 V _{CC} × 0.3	— —	0.50 V _{CC} × 0.3	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
			I _{OH} = -4 mA I _{OH} = -8 mA	4.5	4.4	4.5	—	4.4	—	
				3.0	2.58	—	—	2.48	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
			I _{OL} = 4 mA I _{OL} = 8 mA	4.5	—	0.0	0.1	—	0.1	
				3.0	—	—	0.36	—	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5	—	—	±0.1	—	±1.0	μA	
			5.5	—	—	4.0	—	40.0	μA	

Timing Requirements (input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit
				V _{CC} (V)	Typ.	Limit	
Minimum pulse width (CK)	t _w (L)	—		3.3 ± 0.3	—	5.0	ns
	t _w (H)			5.0 ± 0.5	—	5.0	
Minimum pulse width ($\overline{\text{CLR}}$)	t _w (L)	—		3.3 ± 0.3	—	5.0	ns
				5.0 ± 0.5	—	5.0	
Minimum set-up time	t _s	—		3.3 ± 0.3	—	5.0	ns
				5.0 ± 0.5	—	4.5	
Minimum hold time	t _h	—		3.3 ± 0.3	—	0.0	ns
				5.0 ± 0.5	—	0.5	
Minimum removal time ($\overline{\text{CLR}}$)	t _{rem}	—		3.3 ± 0.3	—	3.0	ns
				5.0 ± 0.5	—	2.5	

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (CK-Q)	t _{pLH} t _{pHL}	—	3.3 ± 0.3	15	—	7.2	11.0	1.0	13.0	ns
				50	—	9.7	14.5	1.0	16.5	
			5.0 ± 0.5	15	—	4.9	7.2	1.0	8.5	
				50	—	6.4	9.2	1.0	10.5	
Propagation delay time ($\overline{\text{CLR}}$ -Q)	t _{pHL}	—	3.3 ± 0.3	15	—	7.4	11.4	1.0	13.5	ns
				50	—	9.9	14.9	1.0	17.0	
			5.0 ± 0.5	15	—	5.1	7.6	1.0	9.0	
				50	—	6.6	9.6	1.0	11.0	
Maximum clock frequency	f _{max}	—	3.3 ± 0.3	15	95	150	—	80	—	MHz
				50	55	85	—	50	—	
			5.0 ± 0.5	15	130	175	—	110	—	
				50	90	120	—	80	—	
Output to output skew	t _{osLH} t _{osHL}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
	5.5 ± 0.5		50	—	—	1.0	—	1.0		
Input capacitance	C _{IN}	—			—	4	10	—	10	pF
Power dissipation capacitance	C _{PD}	(Note 2)			—	29	—	—	—	pF

Note 1: Parameter guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

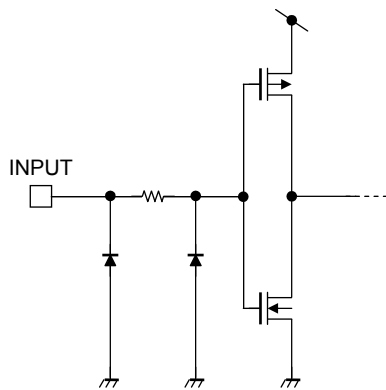
$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per F/F)}$$

And the total C_{PD} when n pcs. of flip flop operate can be gained by the following equation:

$$C_{PD(\text{total})} = 19 + 10 \cdot n$$

Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

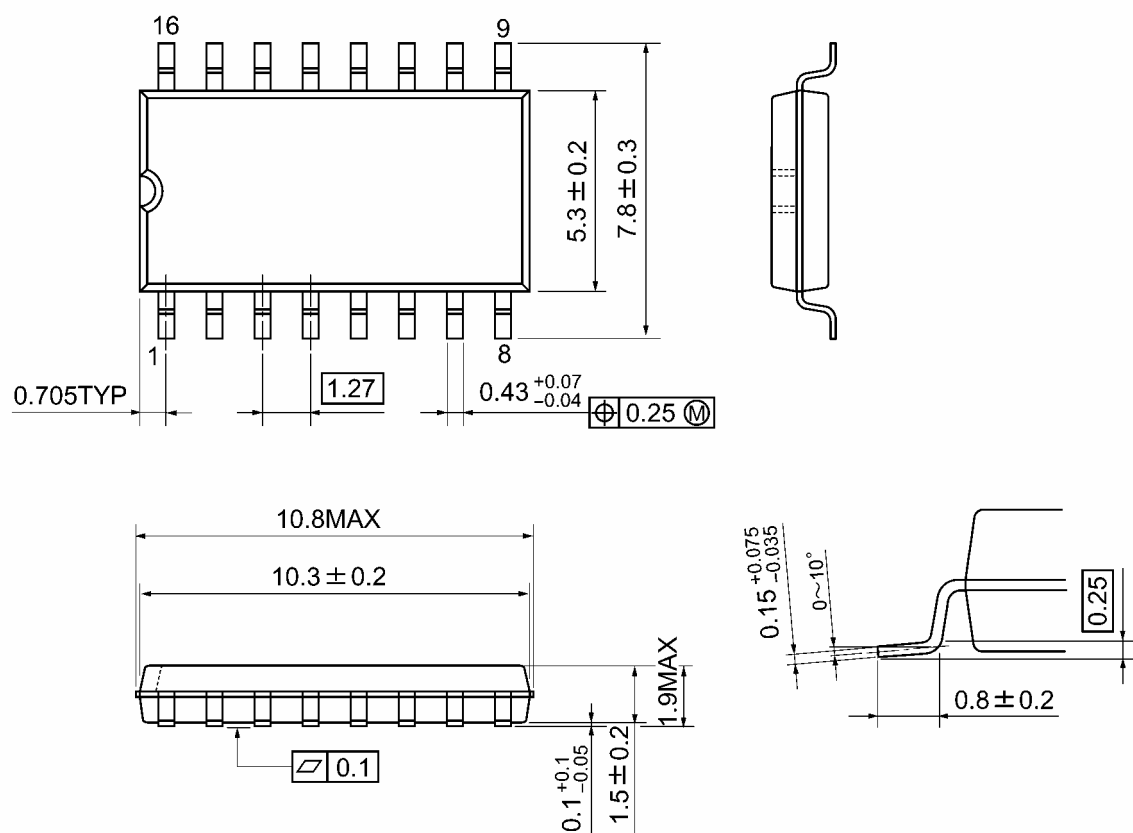
Characteristics	Symbol	Test Condition	Ta = 25°C		Unit	
			V _{CC} (V)	Typ.		Max
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.4	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	−0.4	−0.8	V
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	—	1.5	V

Input Equivalent Circuit


Package Dimensions

SOP16-P-300-1.27A

Unit: mm

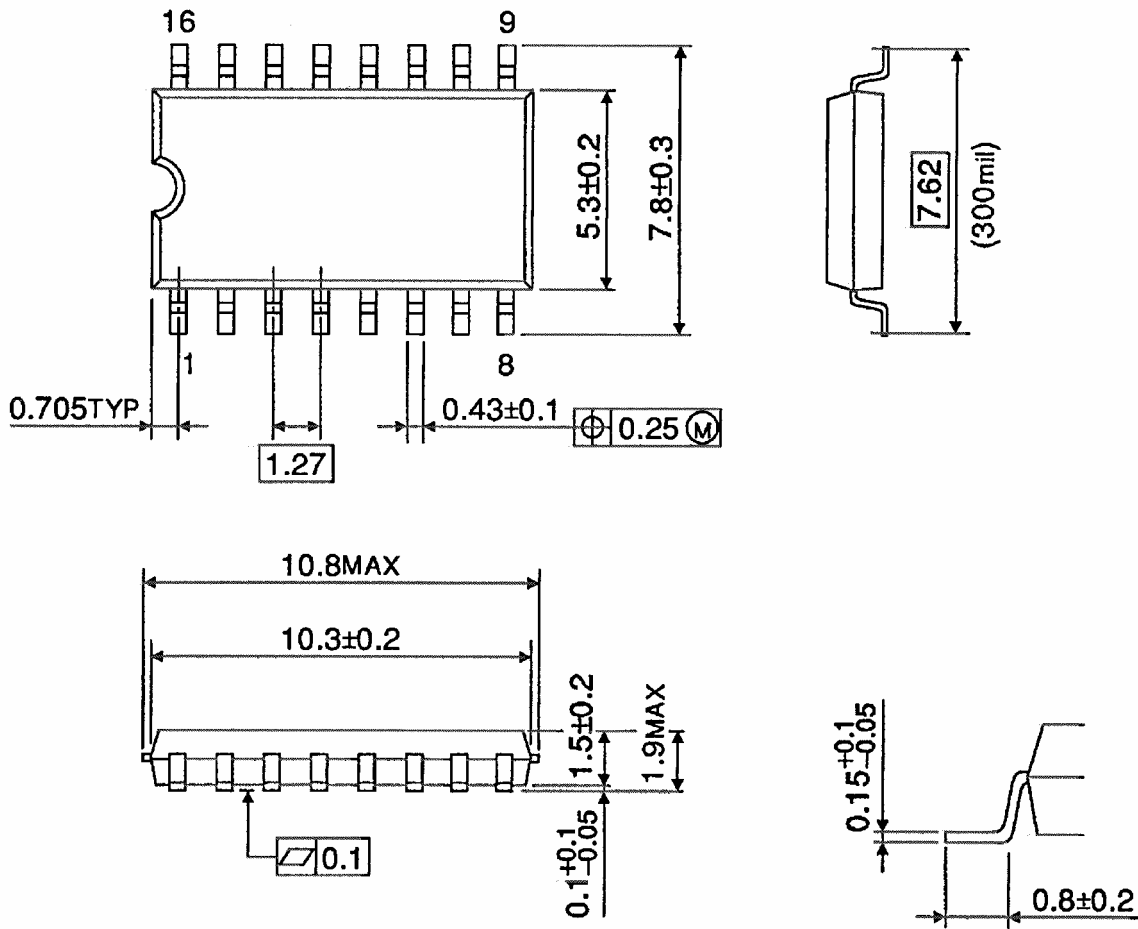


Weight: 0.18 g (typ.)

Package Dimensions

SOP16-P-300-1.27

Unit : mm

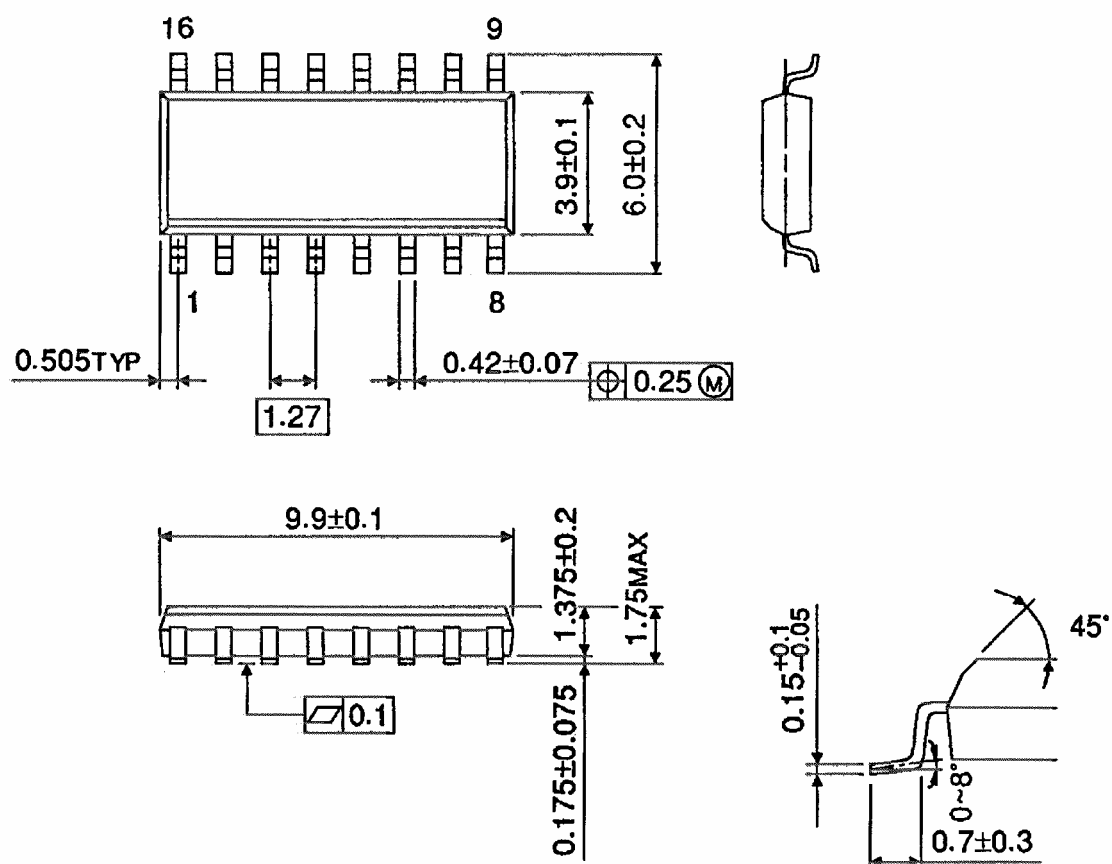


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



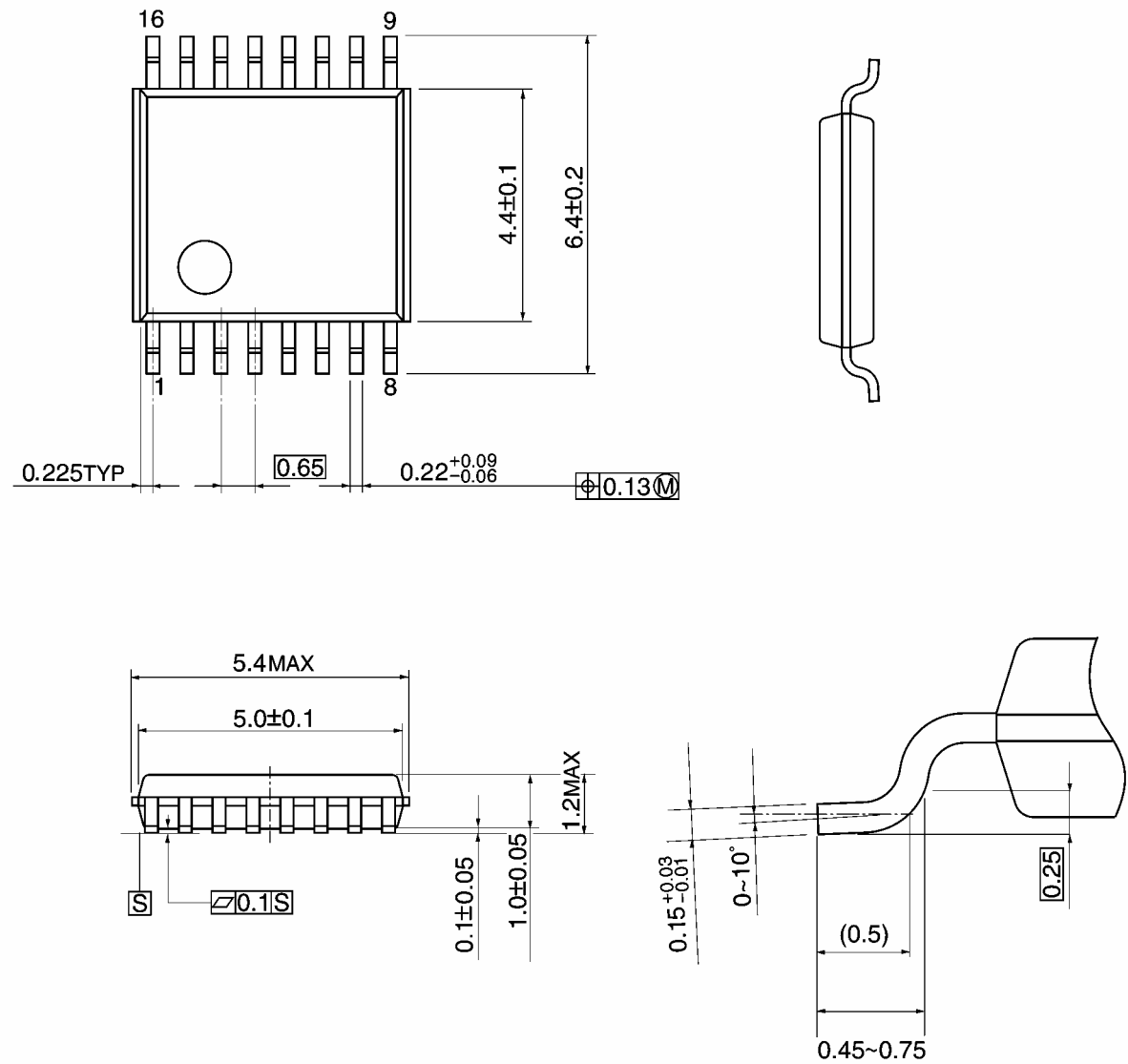
Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages**SOP16-P-300-1.27A SOL16-P-150-1.27 TSSOP16-P-0044-0.65A****RESTRICTIONS ON PRODUCT USE**

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